Diode Semiconductor Device - Page 1 of 1



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Inclosure	Motorial
Inclosure	material:

Glass

**Overall Length:** 

0.570 inches

# **Terminal Length:**

1.000 inches

# **Overall Diameter:**

0.235 inches

#### **Function For Which Designed:**

Transient suppressor

# Joint Electronic Device Engineering Council/jedec/case Outline Designation:

Do-13

#### **Mounting Method:**

Terminal

#### Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

140.0 breakdown voltage, dc and 210.0 drain to substrate voltage

# **Current Rating Per Characteristic:**

30.00 amperes source cutoff current universal and 5.00 microamperes forward current, average peak

# Power Rating Per Characteristic:

1.0 watts small-signal input power, common-collector horsepower metric

# Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius ambient air

# **Test Data Document:**

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

# Terminal Type And Quantity:

2 uninsulated wire lead

# **Specification Data:**

81349-mil-s-19500/507 government specification

# Shelf Life:

N/a

# Unit Of Measure:

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# Demilitarization:

No

Fiig:

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